





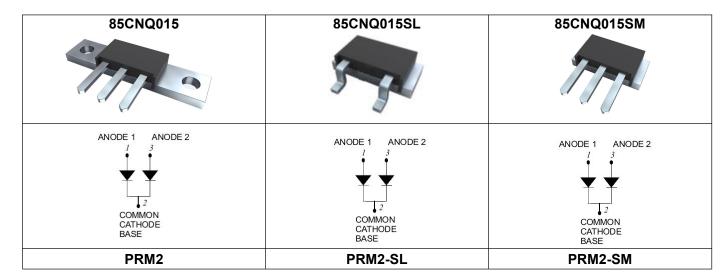
85CNQ015 SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 125°C T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	15	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc =78°C, rectangular wave form	40(Per Leg) 80(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per leg)	I _{FSM}	8.3 ms, half Sine pulse	1020	Α
Non-Repetitive Avalanche Energy (Peg leg)	E _{AS}	T _J =25℃,I _{AS} =2A,L=4.5mH	9	mJ
Repetitive Avalanche Current(Peg leg)	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. V_A =1.5 \times V $_R$ typical	2	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per leg) *	V _{F1}	@ 40A, Pulse, T _J = 25 °C @ 80A, Pulse, T _J = 25 °C	0.36 0.44	0.40 0.50	V
	V _{F2}	@ 40A, Pulse, T _J = 125 °C @ 80A, Pulse, T _J = 125 °C	0.27 0.34	0.32 0.42	V
Reverse Current (Per leg) *	I _{R1}	@V _R = rated V _R , T _J = 25 °C	5	20	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	266	1000	mA
Junction Capacitance (Per leg)	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	3330	3600	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

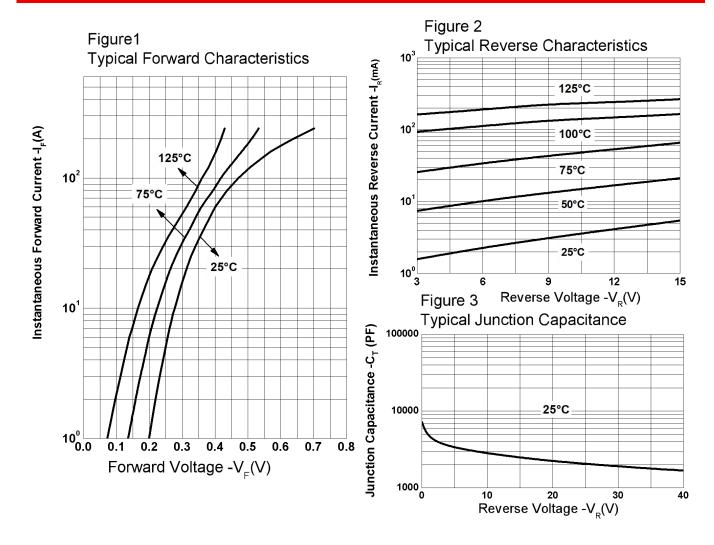
Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +125	°C	
Storage Temperature	T_{stg}	-	-55 to +150	°C	
Typical Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	0.5	°C/W	
Typical Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.25	°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.21	°C/W	
Mounting Torque	T_M		40(min)	Kg-cm	
I woulding rorque	IM	-	58(max)	Ng-CIII	
Case Style	PRM2 PRM2-SL PRM2-SM				



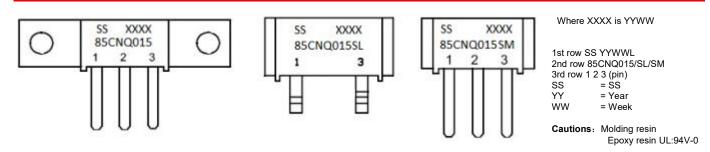




Ratings and Characteristics Curves



Marking Diagram



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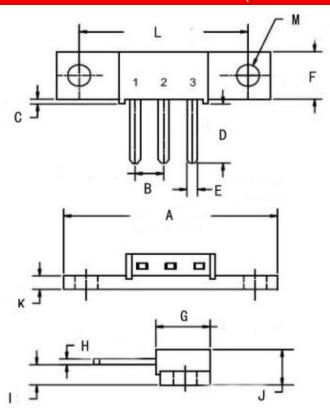


Ordering Information

Device	Package	Approximate Weight(g)	Terminals finish	Base plate finish	Shipping
85CNQ015	PRM2	8.6	Nickel plated	Nickel plated	48pcs / box
85CNQ015S2	PRM2	8.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box
85CNQ015SL	PRM2-SL	5.3	Pure Sn plated	Pure Sn plated	100pcs / box
85CNQ015SLTR	PRM2-SL	5.3	Pure Sn plated	Pure Sn plated	200pcs/ reel
85CNQ015SM	PRM2-SM	5.6	Nickel plated	Nickel plated	48pcs / box
85CNQ015SMS2	PRM2-SM	5.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Mechanical Dimensions PRM2 (Inches/Millimeters)



SYMBOL	Millimeters		Inches		
OTMBOL	Min.	Max.	Min.	Max.	
А	37.72	38.23	1.485	1.506	
В	5.0	08	0.200		
С	0.62	1.02	0.024	0.040	
D	10.38	12.98	0.408	0.511	
E	1.78	2.28	0.070	0.090	
F	8.46	9.06	0.333	0.357	
G	9.24	9.85	0.363	0.388	
Н	0.75	1.15	0.029	0.046	
I	3.19	4.19	0.125	0.165	
J	6.95	7.55	0.273	0.298	
К	2.40	2.60	0.094	0.103	
L	29.51	30.40	1.161	1.197	
М	3.75	4.33	0.147	0.171	

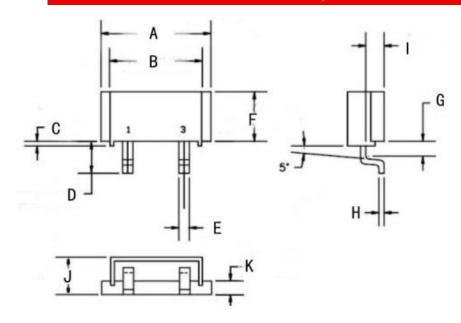
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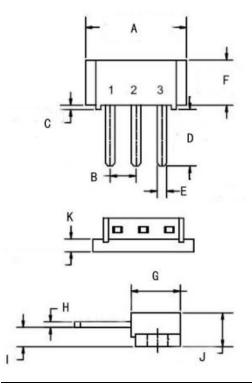


Mechanical Dimensions PRM2-SL (Inches/Millimeters)



SYMBOL	Millimeters		Inches	
OTMBOL	Min.	Max.	Min.	Max.
А	19.70	20.30	0.776	0.799
В	16.51	17.02	0.650	0.670
С	0.62	1.02	0.024	0.040
D	4.97	5.97	0.196	0.235
E	1.78	2.28	0.070	0.090
F	8.46	9.06	0.333	0.357
G	2.04	2.54	0.080	0.100
Н	0.75	1.15	0.029	0.045
I	3.19	4.19	0.125	0.165
J	6.95	7.55	0.274	0.297
К	2.21	2.71	0.087	0.106

Mechanical Dimensions PRM2-SM (Inches/Millimeters)



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
А	19.70	20.30	0.776	0.799
В	5.08		0.200	
С	0.62	1.02	0.024	0.040
D	10.38	12.98	0.408	0.511
Е	1.78	2.28	0.070	0.090
F	8.46	9.06	0.333	0.357
G	9.24	9.85	0.363	0.388
Н	0.75	1.15	0.029	0.045
1	3.19	4.19	0.125	0.165
J	6.95	7.55	0.273	0.298
К	2.21	2.71	0.087	0.106

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